Strontium Bismuth Tantalate Layered Ferroelectric Ceramics: Reaction Kinetics and Thermal Stability

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Abstract: Using BiTaO₄ as the precursor, ferroelectric strontium bismuth tantalate SrBi₂Ta₂O₉ was successfully synthesized. Heating the mixtures of BiTaO₄ and SrCO₃ at 800°C resulted in the entire formation of a single phase SrBi₂. Ta₂O₉. The formation process of this compound was verified to be a direct reaction occurring between the reactants without the presence of intermediates. The conversion of SrBi₂Ta₂O₉ was isothermally analyzed for exploring the reaction kinetics. The results revealed that the formation process was controlled by the diffusion process. Based on the Ginstling–Brounshtein and Jander models, the activation energy of the diffusion process was estimated to be 194.3 kJ mol⁻¹ and 210.7 kJ mol⁻¹, respectively. SrBi₂Ta₂O₉ was found to become unstable when heated at above 1200°C. Once the decomposition process started, this compound was dissociated into SrTa₂O₆ and Bi₂O₃ from surface to interior. © 1998 Elsevier Science Limited and Techna S.r.l. All rights reserved

1 INTRODUCTION

Ferroelectrics which can retain their polarization state after the removal of applied electric field have been intensively investigated for their application to of the nonvolatile memory. The ferroelectric lead zirconate titanate (PZT)-based ceramics have been considered for the memory application; however, when metals are used as electrodes, the PZT system exhibits a serious degradation of the maximum and remnant polarization after long-term switching cycles of electric field.² This fatigue behavior becomes extremely detrimental in terms of practical use. On the other hand, the other ferroelectric material-strontium bismuth tantalate SrBi₂Ta₂O₉ using platinum as electrodes has been found recently to possess excellent fatigue endurance even after 10¹² cycles of operation.^{3,4} Because of this discovery, an entirely new approach for improving the fatigue problem of ferroelectrics has started.

The crystalline structure of SrBi₂Ta₂O₉ belongs to the layered-type perovskite ferroelectrics.⁵ The structure of SrBi₂Ta₂O₉ consists of the perovskitelike TaO₆ octahedron layers and Bi₂O₂ layers. The TaO₆ octahedrons construct continuous layers perpendicular to c-axis direction, but in the c-axis direction these octahedrons are separated by the Bi₂O₂ layers. The presence of the Bi₂O₂ layers has been thought to serve as the shock-absorber for enduring the fatigue of polarization.³ The ceramic form of SrBi₂Ta₂O₉ was first synthesized by Aurivillius,5 and its dielectric properties and phase transformation were later studied by Smolenskii 6 and Subbarao. As for thin films, Desu⁸ and Dat⁹ utilized the pulse laser deposition technique for synthesis, Li¹⁰ used MOCVD process, and Araujo,³ Chu, 11 and Amanuma 12 adopted solution-deposition methods for processing. Excellent electrical properties of SrBi₂Ta₂O₉ thin films were found in the above researches.

SrBi₂Ta₂O₉ has been investigated by several research groups; however, for synthesizing the powder or ceramic form, only the conventional

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process which uses mixed reactants has been undertaken. In our previous study, 13 a novel process using BiTaO4 as the precursor had successfully prepared another layered-perovskite BaBi₂Ta₂O₉. In this new process, the production of intermediates was suppressed, and the formation of BaBi₂Ta₂O₉ was markedly accelerated. obtained powder having a reduced particle size exhibited an enhanced sinterability. For investigating the feasibility of synthesizing SrBi₂Ta₂O₉ by using BiTaO₄ precursors, in the present study, the mixtures of BiTaO₄ and SrCO₃ were used as the starting materials for synthesis. In order to better control the reaction processes, the formation mechanism and reaction kinetics in the formation of SrBi₂Ta₂O₉ were studied. The most applicable kinetic models were determined for analyzing the rate-controlling process and the activation energy of reaction. Furthermore, the thermal stability and the decomposition reaction of SrBi₂Ta₂O₉ at elevated temperatures were also examined.

2 EXPERIMENTAL

BiTaO₄ and SrCO₃ were used as the starting materials for synthesizing SrBi₂Ta₂O₉. For preparing the BiTaO₄ precursors, equal moles of reagent-grade Bi₂O₃ and Ta₂O₅ were ball-milled in ethanol in a polyethylene jar for 48 h. Following drying in a rotary evaporator under reduced pressure, the dried powder was heated at 900°C for 2 h to obtain pure BiTaO₄. The obtained BiTaO₄ powder was subsequently mixed in proportion with SrCO₃, followed by the analogous ball-milling and drying processes as described above. Then the dried powder was used in the following experiments.

The mixtures of BiTaO₄ and SrCO₃ were subjected to differential thermal analysis (DTA) and thermogravimetry analysis (TGA) for tracing the reaction processes. The heating rate was 10° C min⁻¹ and alumina powder was used as reference. For realizing the phase change during reaction, the mixtures were heated in an electric furnace at the same heating rate as that in the thermal analysis, and were quenched in air at various temperatures. The change of the phase formation in the quenched specimens was identified via X-ray powder diffraction (XRD) analysis using CuK_{\pi} radiation. The microstructures of the quenched specimens were observed using a scanning electronic microscope (SEM).

In order to explore the reaction kinetics of SrBi₂Ta₂O₉, the mixed powder was isothermally heated in TGA. The weight loss of the specimens was automatically recorded by a personal computer.

The weight loss at each reaction condition was calculated and converted into the fractional conversion of reaction. For examining the thermal stability of $SrBi_2Ta_2O_9$, the synthesized pure compound were pressed into pellets, and these pellets were heated at temperatures ranging from 1100°C to 1300°C. The compounds formed on the surface and in the bulk of the heated specimens were identified via XRD.

3 RESULTS AND DISCUSSION

3.1 Formation process of SrBi₂Ta₂O₉

Figure 1 illustrates the TGA and DTA curves of the starting material of SrBi₂Ta₂O₉ from room temperature to 1100°C. On the TGA curve the specimen weight gradually decreased at 600°C and above, and the total weight loss increased to be around 4.1% at 750°C. No further weight loss was found at higher temperatures. On the DTA curve a broad endotherm was observed at temperature ranging from 600°C to 750°C. This temperature range was the same as that of weight loss. For realizing the reaction mechanism, the starting materials were heated and quenched at various temperatures. The representative XRD patterns for quenched specimens are shown in Fig. 2; in addition, Fig. 3 illustrates the relative content of each phase against the quenching temperature. At 500°C only the reactants SrCO₃ and BiTaO₄ were present, indicating that no reactions occurred. From 600°C a small amount of SrBi₂Ta₂O₉ started to produce. With the rise in heating temperatures, the amount of SrBi₂Ta₂O₉ rapidly increased;

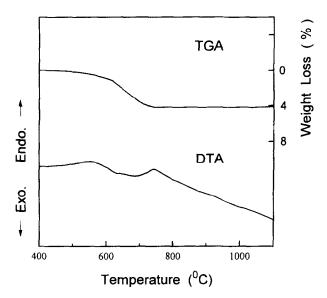


Fig. 1. Differential thermal analysis and thermogravimetry analysis of the starting materials of SrBi₂Ta₂O₉.

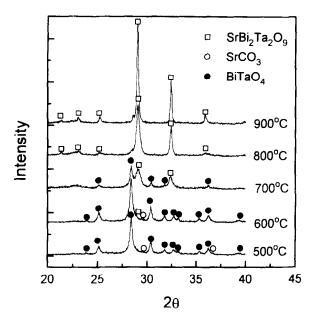


Fig. 2. X-ray diffraction intensity of the starting materials of SrBi₂Ta₂O₉ heated at various temperatures.

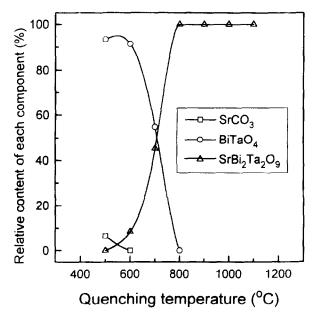


Fig. 3. Relative contents of the resulting compounds during heating the starting materials of SrBi₂Ta₂O₉ at various temperatures.

whereas those amounts of BiTaO₄ and SrCO₃ correspondingly decreased. When the temperature reached 800°C, both reactants were entirely consumed, revealing that the formation of SrBi₂Ta₂O₉ was complete. On further heating to 900°C, the crystallinity of this compound was enhanced. The above XRD results indicated that SrBi₂Ta₂O₉ was successfully synthesized via the new reaction routes using BiTaO₄ as the precursor. Furthermore, the high reactivity between BiTaO₄ and SrCO₃ when the heating temperature reached 800°C resulted in the complete formation of SrBi₂Ta₂O₉. SEM analysis showed that the synthesized SrBi₂Ta₂O₉ powder had an uniform morphology. The particle size

of the 800° C-quenched sample was around 0.05– $0.15\,\mu m$, and that of the 900° C-quenched sample was enlarged to 0.1– $0.2\,\mu m$.

According to the results of Figs 2 and 3, the weight loss on TGA in Fig. 1 was ascribed to the release of carbon dioxide from SrCO₃ for producing SrBi₂Ta₂O₉, and meanwhile the formation of SrBi₂Ta₂O₉ resulted in the endotherm on DTA. Based on the results in Fig. 3, the reaction mechanism of SrBi₂Ta₂O₉ was confirmed to be a direct reaction occurring between two reactants without the presence of any intermediate compounds. Therefore, the formation of SrBi₂Ta₂O₉ can be elucidated by the following equation:

$$SrCO_3 + 2BiTaO_4 \rightarrow SrBi_2Ta_2O_9 + CO_2$$
 (1)

The above equation satisfies the requirement of mass balance.

3.2 Reaction kinetics of SrBi₂Ta₂O₉

The formation of SrBi₂Ta₂O₉ is associated with the vaporization of carbon dioxide from SrCO₃ as expressed in eqn (1), therefore the data of weight loss can be used to calculate the conversion in reactions. The starting materials were isothermally heated at 600, 630, and 660°C for 60 min. The percentage weight loss at each temperature is plotted against reaction time as shown in Fig. 4. This figure indicates that when the reaction time was fixed, the weight loss increased with higher temperatures. Based on eqn (1), the theoretical weight loss is 4.17% when the entire reaction is complete. Therefore the fractional conversion (α) of eqn (1) can be

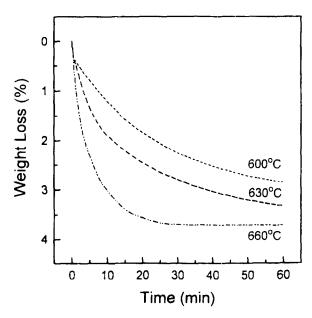


Fig. 4. Weight loss of the starting materials heated at 600, 630, and 660°C, respectively.

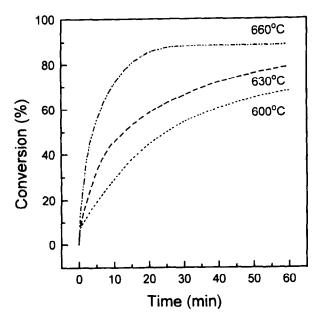


Fig. 5. Conversion ratio of SrBi₂Ta₂O₉ vs reaction time at 600, 630, and 660°C, respectively.

defined as being the ratio of the experimental weight loss to the theoretical weight loss. Figure 5 illustrates the relation between the conversion ratios and reaction conditions. At all three temperatures, the conversion ratio monotonously rose with longer reaction time. It is noted that at the same reaction period, the conversion increased with a rise in the heating temperature. After reacting for 60 min, the conversion ratios at 600 and 630°C were 68 and 77%, respectively. On the other hand, the conversion at 660°C reached nearly around 89% after only 25 min of reaction. Figure 5 indicates that the conversion was enhanced with an increase in reaction temperature and time.

In order to analyze the reaction kinetics of SrBi₂Ta₂O₉, the Hancock and Sharps' method¹⁴ based on the Avrami-Erofe'ev equation^{15,16} was adopted. According to this method, a generalized equation is applicable to identify the classification of reaction kinetics. The linear form of this equation is expressed as

$$\ln(-\ln(1-\alpha)) = \ln B + m \ln t \tag{2}$$

where α is the conversion ratio, t the reaction time, and B a constant which is determined by nucleation frequency and grain growth rate. The slope m obtained by plotting the left-hand term in eqn (2) against $\ln t$ is a characteristic value depending on the controlling mechanism in solid-state reactions. When m = 0.54 - 0.62, the mechanism belongs to the diffusion-controlled type. For m = 1.0 - 1.24, a zero-order, first-order, or phase-boundary controlled mechanism is implied. When m = 2.0 - 3.0, the reaction mechanism is classified to be the nucleation and growth-controlled type.

Figure 6 shows $\ln(-\ln(1-\alpha))$ plotted against vs In (time), and three straight lines were obtained as a result. The values of m at 600, 630, and 660° C were estimated to be 0.61, 0.61, and 0.66, respectively. According to Hancock and Sharps' study,14 the type of diffusion-controlled mechanism is considered to dominate the reaction of SrBi₂Ta₂O₉. diffusion-controlled models,14 Among the considering that the reactions took place among particles in three-dimension, the Ginstling-Brounshtein¹⁷ and Jander's¹⁸ models were chosen to fit the relation between conversion and reaction time. The former model is expressed as

$$1 - 2\alpha/3 - (1 - \alpha)^{2/3} = kt$$
 (3)

and the latter one is expressed as

$$[1 - (1 - \alpha)^{1/3}]^2 = kt \tag{4}$$

where k is the reaction rate constant. The above two functions of α were plotted against reaction time, and the linearity coefficients and the values of k for eqns (3) and (4) are summarized in Table 1. The data in this table indicate that the lines derived from both Ginstling–Brounshtein and Jander's models exhibited good linearity at all three temperatures. In view of the fact that eqns (3) and (4) hold well throughout the reaction process, the Ginstling–Brounshtein and Janders' models can properly describe the reaction mechanism of SrBi₂Ta₂O₉. Using the data of k listed in Table 1 and Arrhenius's equations cited below:

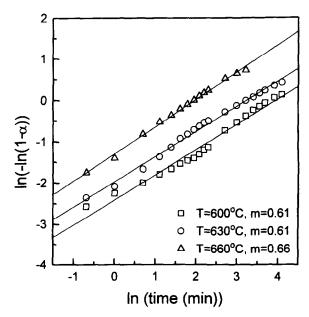


Fig. 6. Plot of $\ln (-\ln(1-\alpha))$ vs $\ln t$ for the formation process of $SrBi_2Ta_2O_9$.

Table 1. Reaction rate constant (k) and the linearity coefficient (R) of the function of conversion with reaction time based on the Ginstling-Brounshtein and Jander's models

Heating temperature (°C)	Ginstling-Brounshtein model		Jander's model	
	k(min ¹)	R	k(min 1)	R
600	0.0014	0.996	0.0018	0.996
63 0	0.0025	0.995	0.0032	0.998
660	0.0081	0.991	0.0012	0.997

$$k = k_0 \exp(-E/RT) \tag{5}$$

the activation energy (E) of the reaction can be derived. Figure 7 illustrates the plot of log(k) vs 1/T for both models. From the slope of the line in Fig. 7, the activation energy for SrBi₂Ta₂O₉ formation was calculated to be 210.7 kJ mol⁻¹ for Jander's model, and 194.3 kJ mol⁻¹ for Ginstling–Brounshtein model. Taking possible experimental errors into consideration, these two derived activation energies are accurately quite close.

3.3 Decomposition of SrBi₂Ta₂O₉

For examining the thermal stability of SrBi₂Ta₂O₉, the pressed SrBi₂Ta₂O₉ pellets were heated at elevated temperatures. The XRD patterns of the ground powder of the heated pellets are shown in Fig. 8. After 1100°C heating, only SrBi₂Ta₂O₉ was identified; however, when the temperature was raised to 1250°C, SrTa₂O₆ was found to coexist with SrBi₂Ta₂O₉. The appearance of SrTa₂O₆ was caused by the thermal decomposition of SrBi₂. Ta₂O₉. After 1300°C heating, the amount of

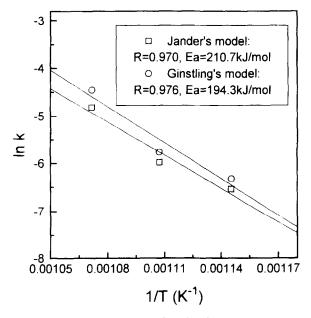


Fig. 7. Plot of ln (k) vs 1/T for the formation process of SrBi₂Ta₂O₉.

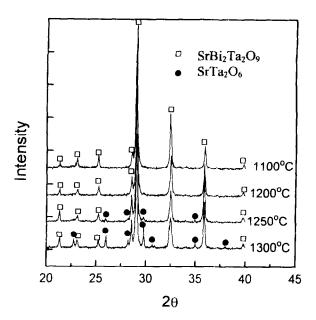


Fig. 8. X-ray diffraction patterns of the ground powder of SrBi₂Ta₂O₉ pellets heated at 1100, 1200, 1250, and 1300°C, respectively.

SrTa₂O₆ further increased with a corresponding reduction in that of SrBi₂Ta₂O₉. The surface of these heated specimens was also examined via XRD. Figure 9 compares the relative amount of SrTa₂O₆ between the bulk and the surface of the heated specimens. The relative amount of SrTa₂O₆ was calculated by dividing the diffraction intensity of the major peak of SrTa₂O₆ at $2\theta = 29.6^{\circ}$ by the sum of the intensity of the major peak of SrBi₂. Ta₂O₉ at $2\theta = 28.4^{\circ}$ and that of SrTa₂O₆ at $2\theta = 29.6^{\circ}$. SrTa₂O₆ was also found to start forming on surface from above 1200° C; moreover, the amount of SrTa₂O₆ on surface was significantly greater than that in bulk. After \$\mathbb{1}300^{\circ}\$C heating,

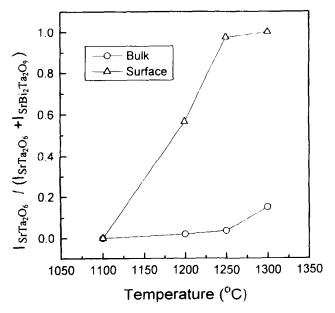
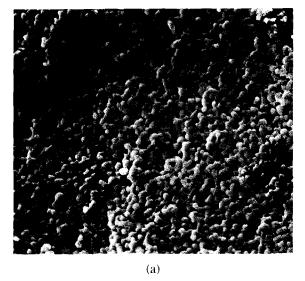


Fig. 9. Relative amounts of SrTa₂O₆ present in the bulk and on the surface of SrBi₂Ta₂O₉ pellets at various heating temperatures.

$$SrBi_2Ta_2O_9 \rightarrow SrTa_2O_6 + Bi_2O_3 \tag{6}$$



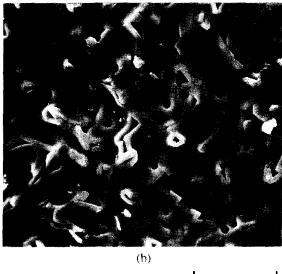


Fig. 10. Scanning electron micrographs of the SrBi₂Ta₂O₉ pellets heated at (a) 1100°C and (b) 1250°C.

10 um

only SrTa₂O₆ was found on the specimen surface. On the other hand, merely 15% SrTa₂O₆ was formed in bulk.

The surface microstructures of the specimens heated at 1100 and 1250°C are shown Fig. 10. At 1100°C (before decomposition), the microstructure appeared to be uniform, and SrBi₂Ta₂O₉ grains with a size of around 0.6 μm were observed. When SrBi₂Ta₂O₉ became decomposed, the microstructure drastically varied. Observing in the 1250°C heated specimen as shown in Fig. 10(b), the grain size rapidly increased to 2–8 μm, and the shape of these grains became rather irregular. From the EDS analysis, the composition of these grains was found to primarily consist of strontium and tantalum with a ratio of around 1:2; therefore, these grains were confirmed to be SrTa₂O₆.

According to the above results, the decomposition reaction of SrBi₂Ta₂O₉ can be expressed via a balanced stoichiometric equation as below:

Since the amount of SrTa₂O₆ on surface is greater than that in bulk, it is reasonable to suggest that the decomposition process of SrBi₂Ta₂O₉ begins from the surface of specimens. At the temperatures where the decomposition of SrBi₂Ta₂O₉ occurs, the vapour pressure of Bi₂O₃ is quite high. As SrBi₂. Ta₂O₉ gets decomposed, Bi₂O₃ will evaporate out gradually. On the specimen surface Bi₂O₃ is able to easily to evaporate out from specimens; therefore, the decomposition process starts from specimen surface. Based on the above results, in attempt to prevent the decomposition of SrBi₂Ta₂O₉, reducing the heating temperatures to be below 1200°C and increasing the atmosphere of bismuth in the heating environment are considered to be practicable strategies.

4 CONCLUSIONS

Ferroelectric layered-perovskite SrBi₂Ta₂O₉ was successfully prepared through a new process using BiTaO₄ as the precursor. Heating the mixtures of BiTaO₄ and SrCO₃ at 800°C resulted in the formation of a single phase of SrBi₂Ta₂O₉. During the reaction process, no intermediate phase was observed, revealing that the formation process was a direct reaction between two constituent compounds. Through the isothermal analysis of the reaction kinetics, the controlling reaction in the formation process of SrBi₂Ta₂O₉ was determined to be the diffusion process. The diffusion-controlled models using Ginstling-Brounshtein and Jander theories were found to well fit the experimental results. Based on Ginstling-Brounshtein and Jander models, the activation energy of the diffusion process was calculated to 194.3 kJ mol⁻¹ and 210.7 kJ mol⁻¹, respectively. The crystalline structure of SrBi₂Ta₂O₉ was found to remain stable at temperatures up to 1100°C. However, this compound became unstable from 1200°C, and dissociated into SrTa₂O₆ and Bi₂O₃. The decomposition process started from the surface of specimens and subsequently progressed towards the interior.

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